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## **Dual Common Cathode Schottky Rectifier**

### **FEATURES**

- Low power loss, high efficiency
- Guardring for overvoltage protection
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

### MECHANICAL DATA

#### Case: TO-220AB

Molding compound, UL flammability classification rating 94V-0

Base P/N with suffix "G" on packing code - halogen-free

Base P/N with prefix "H" on packing code - AEC-Q101 qualified

Terminal: Matte tin plated leads, solderable per JESD22-B102

Meet JESD 201 class 1A whisker test,

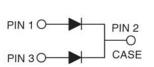
with prefix "H" on packing code meet JESD 201 class 2 whisker test **Polarity:** As marked

Mounting torque: 5 in-lbs maximum

Weight: 1.9 g (approximately)











		MBR	MBR	MBR	MBR	MBR	MBR	MBR	
PARAMETER	SYMBOL	3035 CT	3045 СТ	3050 СТ	3060 CT	3090 CT	30100 CT	30150 СТ	UNIT
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	35	45	50	60	90	100	150	V
Maximum RMS voltage	V <sub>RMS</sub>	24	31	35	42	63	70	105	V
Maximum DC blocking voltage	V <sub>DC</sub>	35	45	50	60	90	100	150	V
Maximum average forward rectified current I <sub>F(AV)</sub>			30				А		
Peak repetitive forward current (Rated VR, Square wave, 20KHz)	I <sub>FRM</sub>	30				А			
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	200				А			
Peak repetitive reverse surge current (Note 1)	I <sub>RRM</sub>	1.0 0.5				А			
Maximum instantaneous forward voltage (Note 2) I <sub>F</sub> =15A, T <sub>J</sub> =25 $^\circ\mathbb{C}$		0	.7	0.	77	0.	84	0.95	
I <sub>F</sub> =15A, T <sub>J</sub> =125℃	V <sub>F</sub>	0	.6	0.	67	0.	70	0.92	V
I <sub>F</sub> =30A, T <sub>J</sub> =25℃		0.	82		-	0.	94	1.02	
I <sub>F</sub> =30A, T <sub>J</sub> =125℃		0.	73		-	0.	82	0.98	
Maximum reverse current @ rated VR T_=25 °C	I <sub>R</sub>	0.2 0.1							
T <sub>J</sub> =125 ℃		1	5	10		7	7.5 5		mA
Voltage rate of change (Rated V <sub>R</sub> )	dV/dt	10000				V/µs			
Typical thermal resistance	R <sub>θJC</sub>	1.0 1.5			°C/W				
Operating junction temperature range	TJ	- 55 to +150			0 <sup>0</sup> C				
Storage temperature range	T <sub>STG</sub>	- 55 to +150				0 <sup>0</sup>			

Note 1: tp = 2.0 µs, 1.0KHz

Note 2: Pulse test with PW=300µs, 1% duty cycle



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ORDERING INFORMATION						
PART NO.	AEC-Q101	PACKING CODE	<b>GREEN COMPOUND</b>	PACKAGE	PACKING	
	QUALIFIED	PACKING CODE	CODE	PACKAGE	FACKING	
MBR30xxCT	Prefix "H"	C0	Suffix "G"	TO-220AB	50 / Tube	
Note 1: "xx" defines voltage from 35V (MBR3035CT) to 150V (MBR30150CT)						

"xx" defines voltage from 35V (MBR3035CT) to 150V (MBR30150CT) 1:

EXAMPLE							
PREFERRED P/N	PART NO.	AEC-Q101 QUALIFIED	PACKING CODE	GREEN COMPOUND CODE	DESCRIPTION		
MBR3060CT C0	MBR3060CT		C0				
MBR3060CT C0G	MBR3060CT		C0	G	Green compound		
MBR3060CTHC0	MBR3060CT	Н	C0		AEC-Q101 qualified		

### **RATINGS AND CHARACTERISTICS CURVES**

(TA=25°C unless otherwise noted)

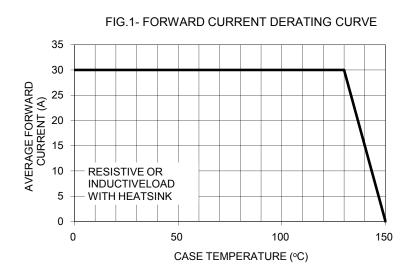
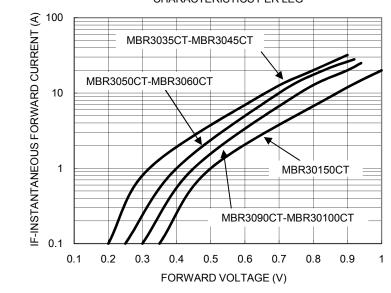
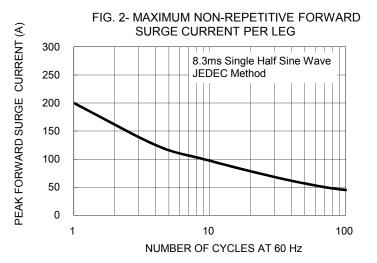
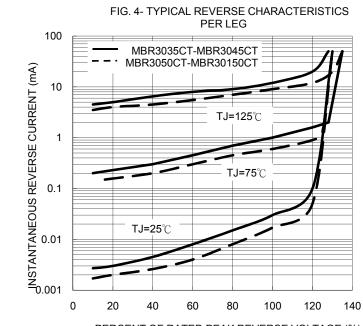


FIG. 3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS PER LEG







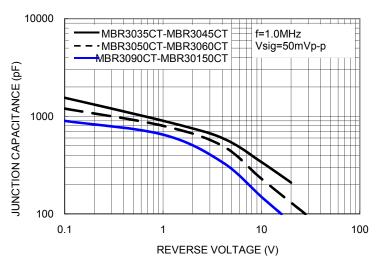
PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

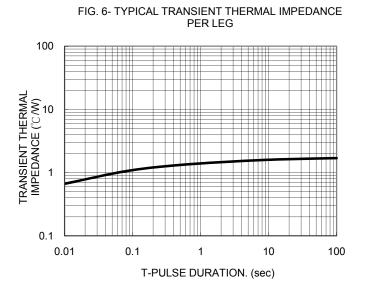


### MBR3035CT thru MBR30150CT

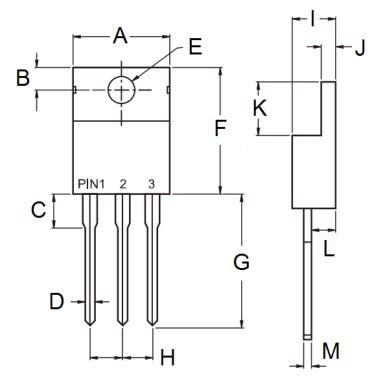
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FIG. 5- TYPICAL JUNCTION CAPACITANCE PER LEG





### PACKAGE OUTLINE DIMENSIONS



DIM.	Unit	(mm)	Unit (inch)		
	Min	Min Max		Max	
А	-	10.50	-	0.413	
В	2.62	3.44	0.103	0.135	
С	2.80	4.20	0.110	0.165	
D	0.68	0.94	0.027	0.037	
E	3.54	4.00	0.139	0.157	
F	14.60	16.00	0.575	0.630	
G	13.19	14.79	0.519	0.582	
Н	2.41	2.67	0.095	0.105	
I	4.42	4.76	0.174	0.187	
J	1.14	1.40	0.045	0.055	
К	5.84	6.86	0.230	0.270	
L	2.20	2.80	0.087	0.110	
М	0.35	0.64	0.014	0.025	

### MARKING DIAGRAM



- = Marking Code
- = Green Compound
- = Date Code
- = Factory Code



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MBR30100CTMBR3035CTMBR3045CTMBR3050CTMBR3060CTMBR3090CTMBR30150CT C0MBR3045CT C0MBR3035CTHC0MBR30150CTHC0MBR3045CTHC0MBR3090CTHC0MBR3050CTHC0MBR3060CTHC0MBR30100CTHC0MBR30100CTHC0MBR30100CTHC0MBR30100CTHC0